# 2SD1490

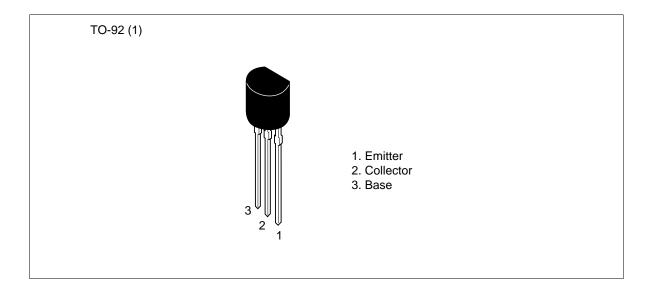
# Silicon NPN Epitaxial

# **HITACHI**

### **Application**

- Low frequency power amplifier
- Complementary pair with 2SB1059

### **Outline**





### 2SD1490

### **Absolute Maximum Ratings** (Ta = 25°C)

| Item                         | Symbol         | Ratings     | Unit |
|------------------------------|----------------|-------------|------|
| Collector to base voltage    | $V_{CBO}$      | 70          | V    |
| Collector to emitter voltage | $V_{CEO}$      | 50          | V    |
| Emitter to base voltage      | $V_{EBO}$      | 6           | V    |
| Collector current            | I <sub>c</sub> | 1           | А    |
| Collector power dissipation  | P <sub>c</sub> | 0.75        | W    |
| Junction temperature         | Tj             | 150         | °C   |
| Storage temperature          | Tstg           | -55 to +150 | °C   |

### **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

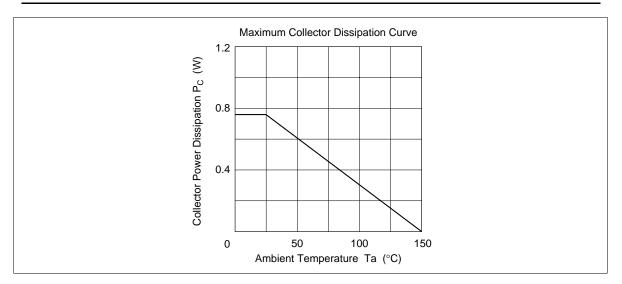
| Item                                    | Symbol                     | Min | Тур | Max | Unit | Test conditions                                       |
|---|----------------------------|-----|-----|-----|------|---|
| Collector to base breakdown voltage     | $V_{(BR)CBO}$              | 70  | _   | _   | V    | $I_{\rm C} = 10 \; \mu A, \; I_{\rm E} = 0$           |
| Collector to emitter breakdown voltage  | $V_{(BR)CEO}$              | 50  | _   | _   | V    | $I_{C}$ = 1 mA, $R_{BE}$ = $\infty$                   |
| Emitter to base breakdown voltage       | $V_{(BR)EBO}$              | 6   | _   | _   | V    | $I_E = 10 \mu A, I_C = 0$                             |
| Collector cutoff current                | I <sub>CBO</sub>           | _   | _   | 1   | μΑ   | $V_{CB} = 80 \text{ V}, I_{E} = 0$                    |
| Emitter cutoff current                  | $I_{EBO}$                  | _   | _   | 0.2 | μΑ   | $V_{EB} = 6 \text{ V}, I_{C} = 0$                     |
| DC current transfer ratio               | $h_{\text{FE}}^{}\star^1}$ | 100 | _   | 500 |      | $V_{CE} = 2 \text{ V}, I_{C} = 0.1 \text{ A}$         |
| Collector to emitter saturation voltage | $V_{\text{CE(sat)}}$       | _   | _   | 0.3 | V    | $I_{C} = 1 \text{ A}, I_{B} = 0.1 \text{ A}$          |
| Gain bandwidth product                  | f <sub>T</sub>             | _   | 80  | _   | MHz  | $V_{CE} = 2 \text{ V}, I_{C} = 10 \text{ mA}$         |
| Collector output capacitance            | Cob                        | _   | 20  | _   | pF   | $V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$ |

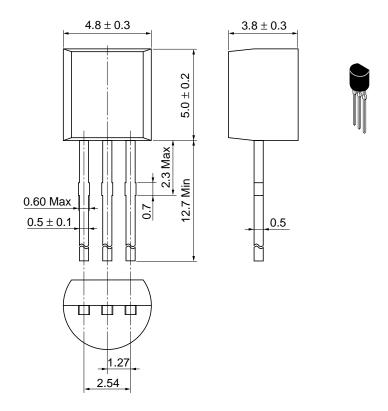
Note: 1. The 2SD1490 is grouped by  $h_{FE}$  as follows.

| В          | С          | D          |
|------------|------------|------------|
| 100 to 200 | 160 to 320 | 250 to 500 |

See characteristic curves of 2SD789.

## 2SD1490





| Hitachi Code             | TO-92 (1) |
|--------------------------|-----------|
| JEDEC                    | Conforms  |
| EIAJ                     | Conforms  |
| Weight (reference value) | 0.25 g    |

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